SEP 0 2 2005

TN

AMENDMENT TRANSMITTAL LETTER Docket No. M4065.0278/P278						
Application No. 09/653,281		Filing Date August 31, 2000		Examiner Richard A. Bo	Examiner tichard A. Booth	
Applicant(s): Kevin L. Beaman, et al.						2812
Invention: USE OF ATOMIC OXIDATION FOR FABRICATION OF OXIDE-NITRIDE-OXIDE STACK FOR FLASH MEMORY DEVICES						
TO THE COMMISSIONER FOR PATENTS Transmitted herewith is an amendment in the above-identified application. The fee has been calculated and is transmitted as shown below.						
CLAIMS AS AMENDED						
	Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate		
Total Claims	33	- 45 =	0	x	_	0.00
Independent Claims	3	- 3 =	0	x		0.00
Multiple Dependent Claims (check if applicable)						
Other fee (please specify):						
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT:						0.00
X Large Entity Small Entity X No additional fee is required for this amendment.						
DICKSTEIN SH 2101 L Street N Washington, DO (202) 828-2232	APIRO MORII W C 20037-1526		Y LLP			



Docket No.: M4065.0278/P278

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Examiner: Richard A. Booth

Kevin L. Beaman, et al.

Application No.: 09/653,281

Art Unit: 2812

Filed: August 31, 2000

For: USE OF ATOMIC OXIDATION FOR

FABRICATING OF OXIDE-NITRIDE-OXIDE STACK FOR FLASH MEMORY DEVICES

AMENDMENT IN RESPONSE TO A NON-FINAL OFFICE ACTION

Commissioner for Patents

MS: <u>Amendment</u> P.O. Box 1450

Alexandria, VA 22313-1450

Dear Sir:

This paper is in response to the non-final Office Action dated July 19, 2005. Please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 8 of this paper.